

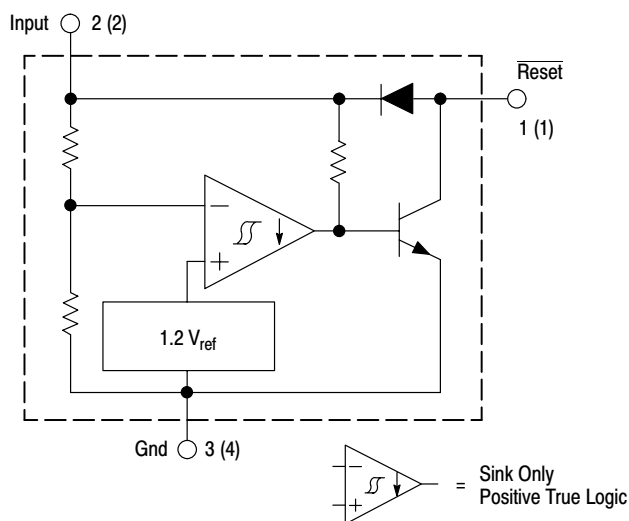
Undervoltage Sensing Circuit

The MC34064 is an undervoltage sensing circuit specifically designed for use as a reset controller in microprocessor-based systems. It offers the designer an economical solution for low voltage detection with a single external resistor. The MC34064 features a trimmed-in-package bandgap reference, and a comparator with precise thresholds and built-in hysteresis to prevent erratic reset operation. The open collector reset output is capable of sinking in excess of 10 mA, and operation is guaranteed down to 1.0 V input with low standby current. These devices are packaged in 3-pin TO-226AA, 8-pin SO-8 and Micro-8 surface mount packages.

Applications include direct monitoring of the 5.0 V MPU/logic power supply used in appliance, automotive, consumer and industrial equipment.

- Trimmed-In-Package Temperature Compensated Reference
- Comparator Threshold of 4.6 V at 25°C
- Precise Comparator Thresholds Guaranteed Over Temperature
- Comparator Hysteresis Prevents Erratic Reset
- Reset Output Capable of Sinking in Excess of 10 mA
- Internal Clamp Diode for Discharging Delay Capacitor
- Guaranteed Reset Operation with 1.0 V Input
- Low Standby Current
- Economical TO-226AA, SO-8 and Micro-8 Surface Mount Packages

Representative Block Diagram



Pin numbers adjacent to terminals are for the 3-pin TO-226AA package. Pin numbers in parenthesis are for the 8-lead packages.

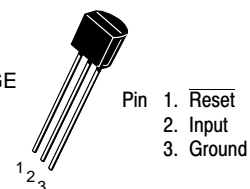
This device contains 21 active transistors.

MC34064 MC33064

UNDERVOLTAGE SENSING CIRCUIT

SEMICONDUCTOR TECHNICAL DATA

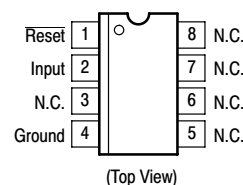
P SUFFIX
PLASTIC PACKAGE
CASE 29
(TO-226AA)



D SUFFIX
PLASTIC PACKAGE
CASE 751
(SO-8)



DM SUFFIX
PLASTIC PACKAGE
CASE 846A
(Micro-8)



ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC34064D-5	$T_A = 0^\circ \text{ to } +70^\circ\text{C}$	SO-8
MC34064DM-5		Micro-8
MC34064P-5		TO-226AA
MC33064D-5	$T_A = -40^\circ \text{ to } +85^\circ\text{C}$	SO-8
MC33064DM-5		Micro-8
MC33064P-5		TO-226AA

MC34064 MC33064

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Input Supply Voltage	V_{in}	-1.0 to 10	V
Reset Output Voltage	V_O	10	V
Reset Output Sink Current (Note 1)	I_{Sink}	Internally Limited	mA
Clamp Diode Forward Current, Pin 1 to 2 (Note 1)	I_F	100	mA
Power Dissipation and Thermal Characteristics			
P Suffix, Plastic Package			
Maximum Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	625	mW
Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	200	$^\circ\text{C/W}$
D Suffix, Plastic Package			
Maximum Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	625	mW
Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	200	$^\circ\text{C/W}$
DM Suffix, Plastic Package			
Maximum Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	520	mW
Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	240	$^\circ\text{C/W}$
Operating Junction Temperature	T_J	+150	$^\circ\text{C}$
Operating Ambient Temperature	T_A		$^\circ\text{C}$
MC34064		0 to +70	
MC33064		-40 to +85	
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$

NOTE: ESD data available upon request.

ELECTRICAL CHARACTERISTICS (For typical values $T_A = 25^\circ\text{C}$, for min/max values T_A is the operating ambient temperature range that applies [Notes 2 and 3] unless otherwise noted.)

Characteristics	Symbol	Min	Typ	Max	Unit
COMPARATOR					
Threshold Voltage					V
High State Output (V_{in} Increasing)	V_{IH}	4.5	4.61	4.7	
Low State Output (V_{in} Decreasing)	V_{IL}	4.5	4.59	4.7	
Hysteresis	V_H	0.01	0.02	0.05	

RESET OUTPUT

Output Sink Saturation	V_{OL}				V
($V_{in} = 4.0\text{ V}$, $I_{Sink} = 8.0\text{ mA}$)		-	0.46	1.0	
($V_{in} = 4.0\text{ V}$, $I_{Sink} = 2.0\text{ mA}$)		-	0.15	0.4	
($V_{in} = 1.0\text{ V}$, $I_{Sink} = 0.1\text{ mA}$)		-	-	0.1	
Output Sink Current (V_{in} , $\overline{\text{Reset}} = 4.0\text{ V}$)	I_{Sink}	10	27	60	mA
Output Off-State Leakage (V_{in} , $\overline{\text{Reset}} = 5.0\text{ V}$)	I_{OH}	-	0.02	0.5	μA
Clamp Diode Forward Voltage, Pin 1 to 2 ($I_F = 10\text{ mA}$)	V_F	0.6	0.9	1.2	V

TOTAL DEVICE

Operating Input Voltage Range	V_{in}	1.0 to 6.5	-	-	V
Quiescent Input Current ($V_{in} = 5.0\text{ V}$)	I_{in}	-	390	500	μA

- NOTES:**
- Maximum package power dissipation limits must be observed.
 - Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
 - $T_{low} = 0^\circ\text{C}$ for MC34064
 $T_{high} = +70^\circ\text{C}$ for MC34064
 -40°C for MC33064
 $+85^\circ\text{C}$ for MC33064

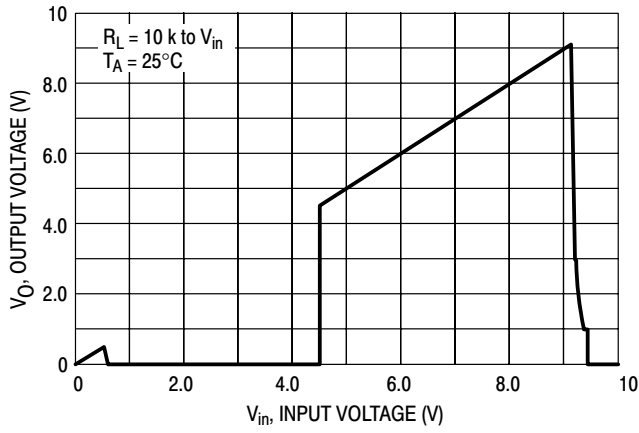


Figure 1. Reset Output Voltage versus Input Voltage

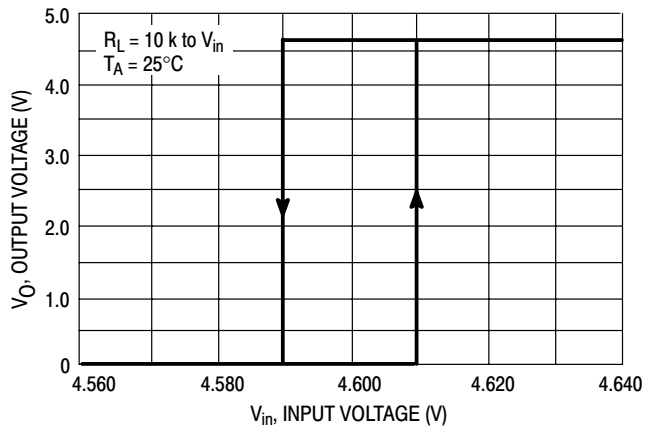


Figure 2. Reset Output Voltage versus Input Voltage

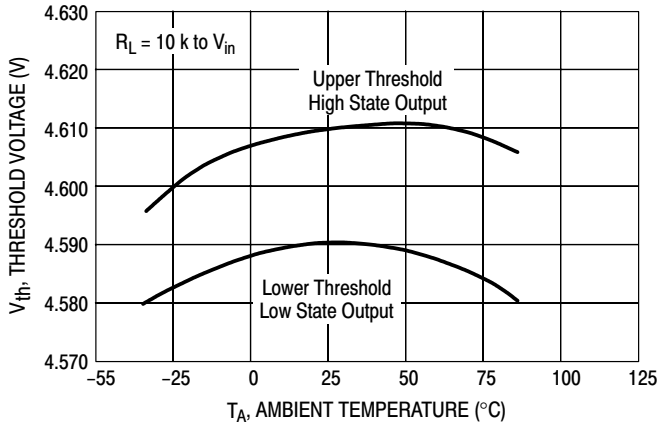


Figure 3. Comparator Threshold Voltage versus Temperature

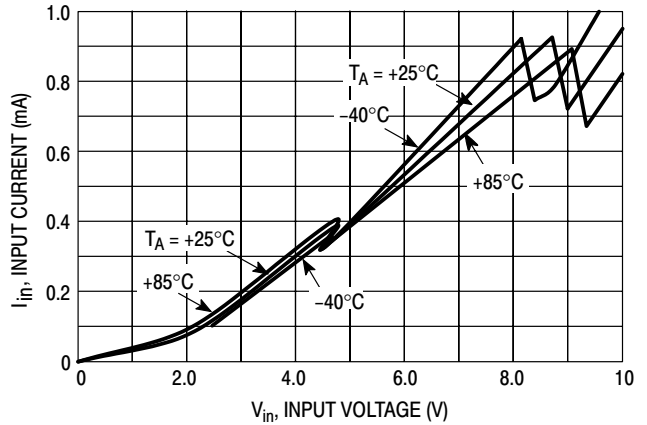


Figure 4. Input Current versus Input Voltage

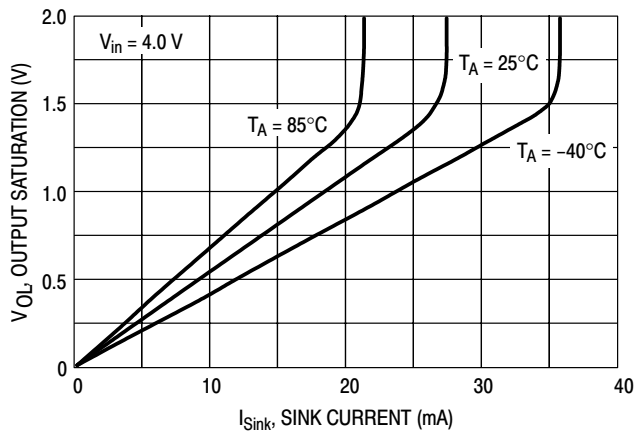


Figure 5. Reset Output Saturation versus Sink Current

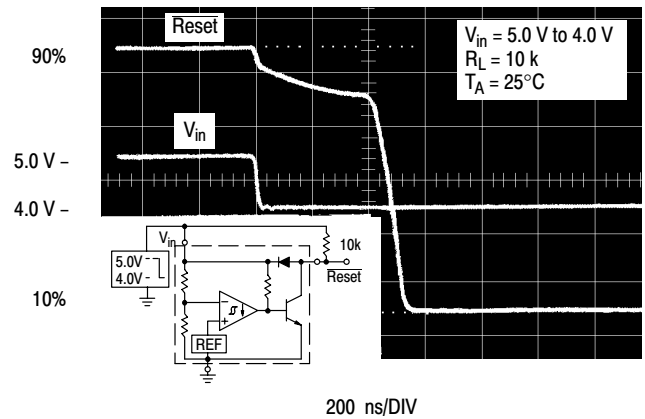


Figure 6. Reset Delay Time

MC34064 MC33064

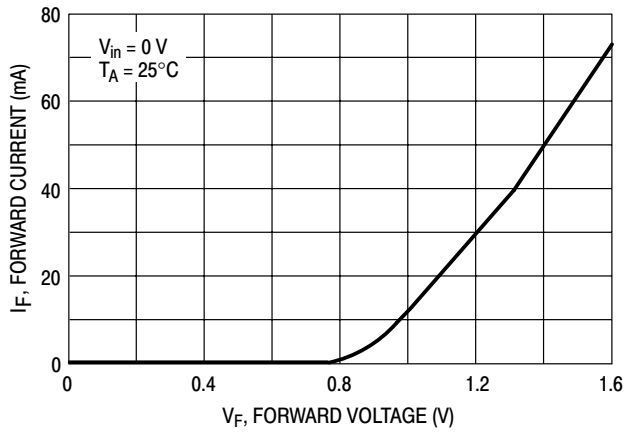


Figure 7. Clamp Diode Forward Current versus Voltage

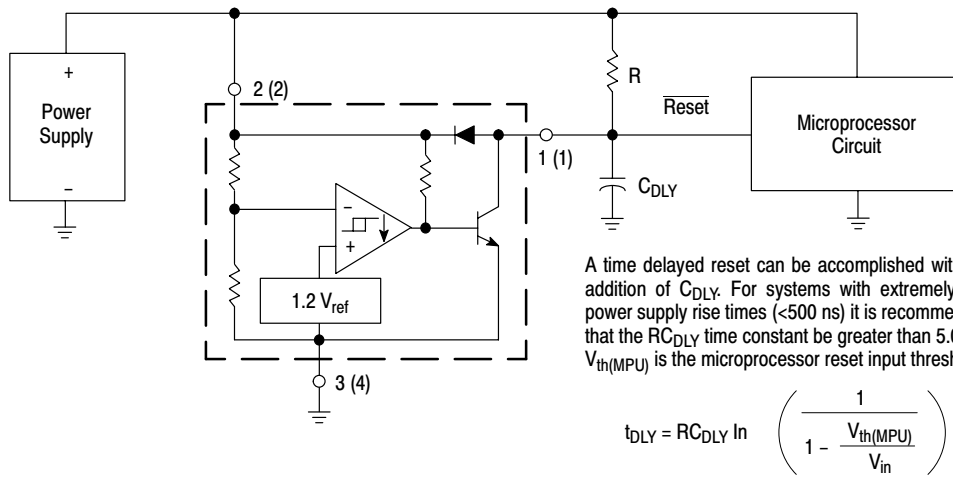


Figure 8. Low Voltage Microprocessor Reset

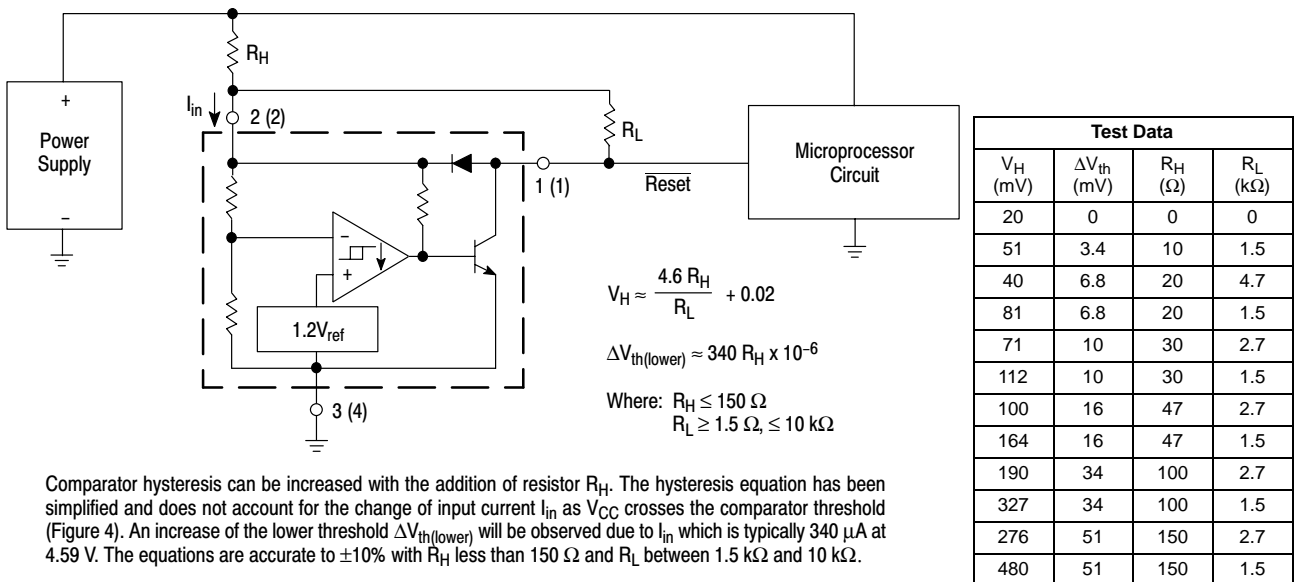


Figure 9. Low Voltage Microprocessor Reset with Additional Hysteresis

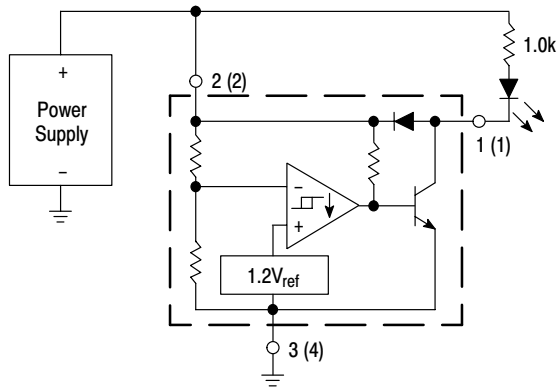


Figure 10. Voltage Monitor

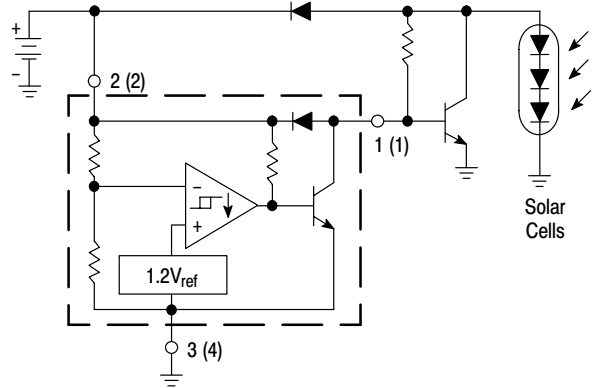
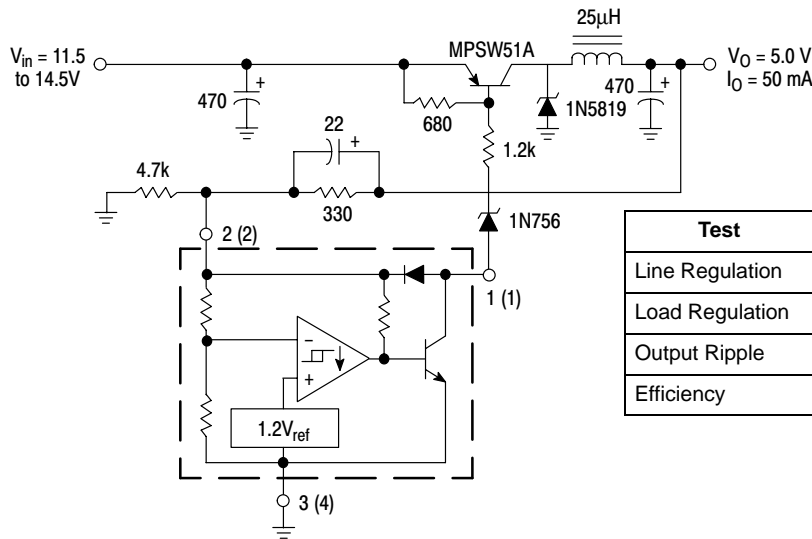
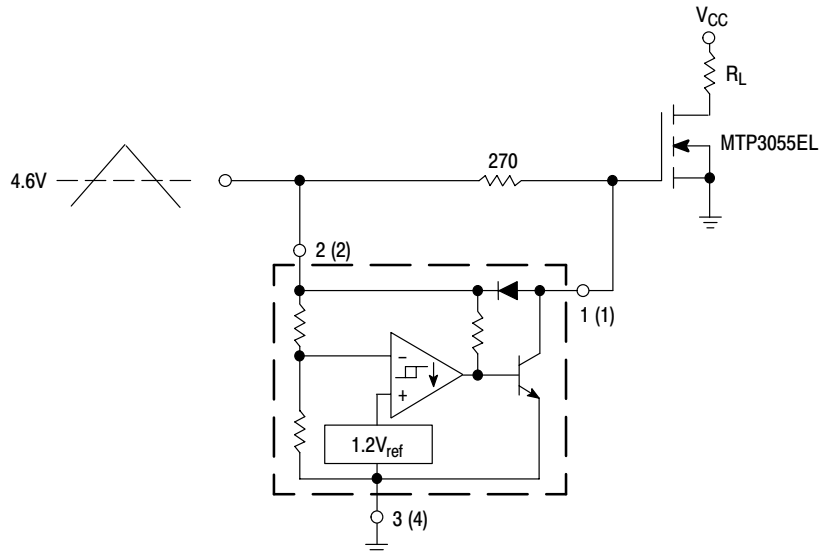


Figure 11. Solar Powered Battery Charger



Test	Conditions	Results
Line Regulation	$V_{in} = 11.5 \text{ V to } 14.5 \text{ V}, I_O = 50 \text{ mA}$	35 mV
Load Regulation	$V_{in} = 12.6 \text{ V}, I_O = 0 \text{ mA to } 50 \text{ mA}$	12 mV
Output Ripple	$V_{in} = 12.6 \text{ V}, I_O = 50 \text{ mA}$	60 mVpp
Efficiency	$V_{in} = 12.6 \text{ V}, I_O = 50 \text{ mA}$	77%

Figure 12. Low Power Switching Regulator



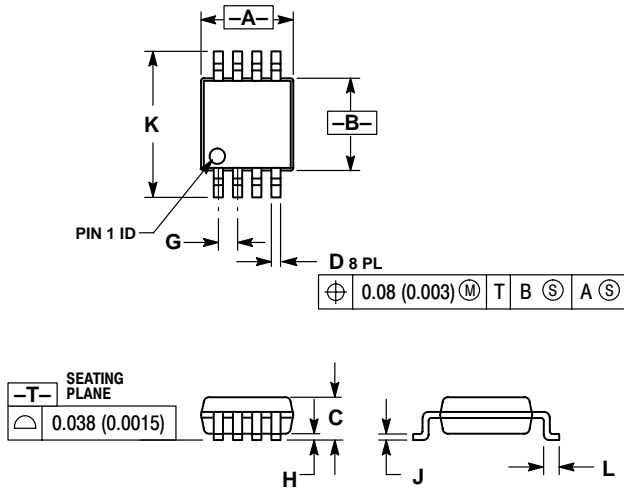
Overheating of the logic level power MOSFET due to insufficient gate voltage can be prevented with the above circuit. When the input signal is below the 4.6 V threshold of the MC34064, its output grounds the gate of the L² MOSFET.

Figure 13. MOSFET Low Voltage Gate Drive Protection

MC34064 MC33064

PACKAGE DIMENSIONS

DM SUFFIX
 PLASTIC PACKAGE
 CASE 846A-02
 (Micro-8)
 ISSUE E



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

		MILLIMETERS		INCHES	
DIM		MIN	MAX	MIN	MAX
A		2.90	3.10	0.114	0.122
B		2.90	3.10	0.114	0.122
C		---	1.10	---	0.043
D		0.25	0.40	0.010	0.016
G		0.65 BSC		0.026 BSC	
H		0.05	0.15	0.002	0.006
J		0.13	0.23	0.005	0.009
K		4.75	5.05	0.187	0.199
L		0.40	0.70	0.016	0.028

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